

The documentation and process conversion measures necessary to comply with this amendment shall be completed by 7 August, 2002.

INCH-POUND

MIL-PRF-19500/697
AMENDMENT 1
7 May 2002

PERFORMANCE SPECIFICATION

SEMICONDUCTOR DEVICE, FIELD EFFECT RADIATION HARDENED
(TOTAL DOSE AND SINGLE EVENT EFFECTS) TRANSISTOR, N-CHANNEL,
SILICON TYPES 2N7478T1 JANTXVR, F, G AND H AND JANSR, F, G AND H

This amendment forms a part of MIL-PRF-19500/697, dated 16 August 2001, and is approved for use by all Departments and Agencies of the Department of Defense.

PAGE 1

1.3, column P_T (1) T_A = +25°C, delete "(1)".

Custodians:
Army - CR
Air Force - 11
DLA - CC

Review activity:
Army - MI
Air Force - 71, 99

Preparing activity:
DLA - CC

(Project 5961-2588)